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# ATP212

## N-Channel Power MOSFET 60V, 35A, 23mΩ, Single ATPAK

### Features

- Low ON-resistance
- 4V drive
- Halogen free compliance
- Large current
- Slim package
- Protection diode in

### Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter                          | Symbol           | Conditions             | Ratings     | Unit |
|------------------------------------|------------------|------------------------|-------------|------|
| Drain-to-Source Voltage            | V <sub>DSS</sub> |                        | 60          | V    |
| Gate-to-Source Voltage             | V <sub>GSS</sub> |                        | ±20         | V    |
| Drain Current (DC)                 | I <sub>D</sub>   |                        | 35          | A    |
| Drain Current (PW≤10μs)            | I <sub>DP</sub>  | PW≤10μs, duty cycle≤1% | 105         | A    |
| Allowable Power Dissipation        | P <sub>D</sub>   | Tc=25°C                | 40          | W    |
| Channel Temperature                | T <sub>ch</sub>  |                        | 150         | °C   |
| Storage Temperature                | T <sub>stg</sub> |                        | -55 to +150 | °C   |
| Avalanche Energy (Single Pulse) *1 | E <sub>AS</sub>  |                        | 19          | mJ   |
| Avalanche Current *2               | I <sub>AV</sub>  |                        | 18          | A    |

Note : \*1 V<sub>DD</sub>=10V, L=100μH, I<sub>AV</sub>=18A

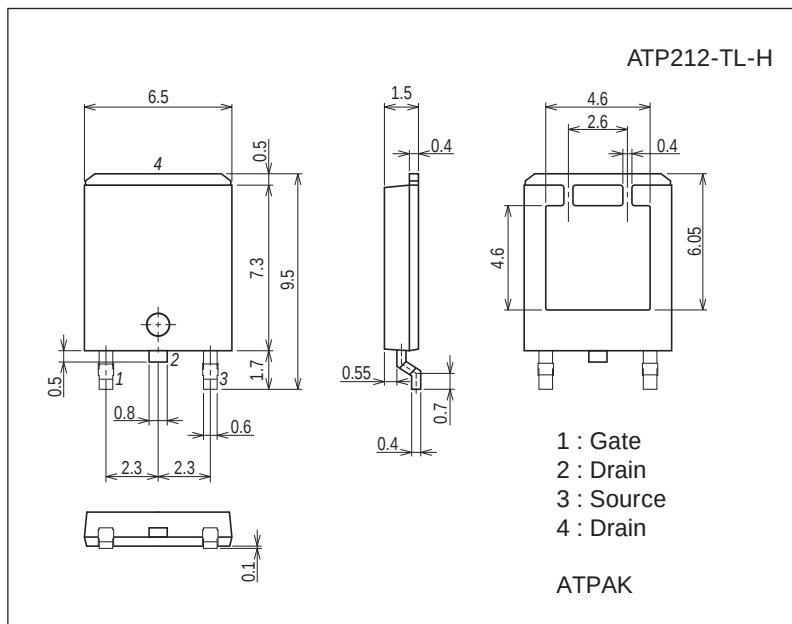
\*2 L≤100μH, Single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### Package Dimensions

unit : mm (typ)

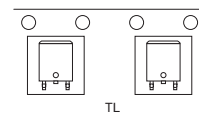
7057-001



### Product & Package Information

- Package : ATPAK
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

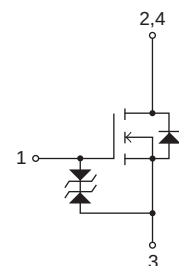
### Packing Type: TL



### Marking



### Electrical Connection

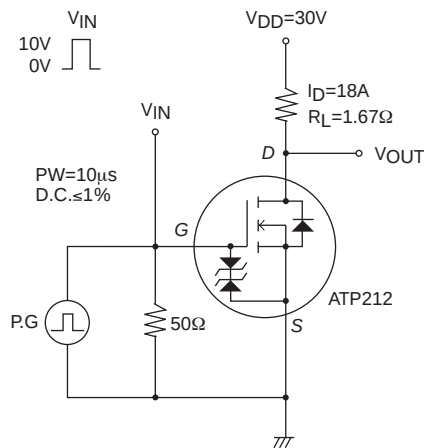


## ATP212

### Electrical Characteristics at Ta=25°C

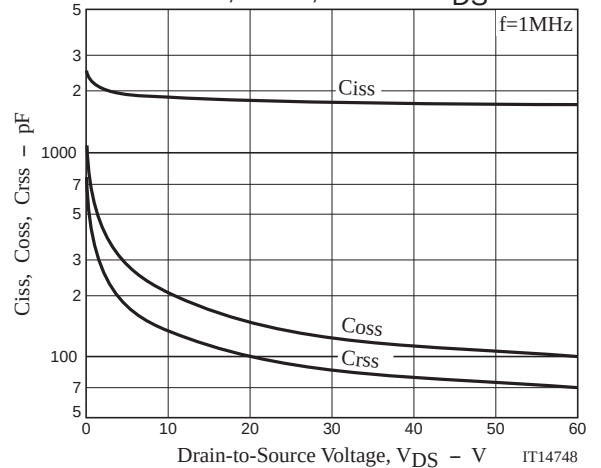
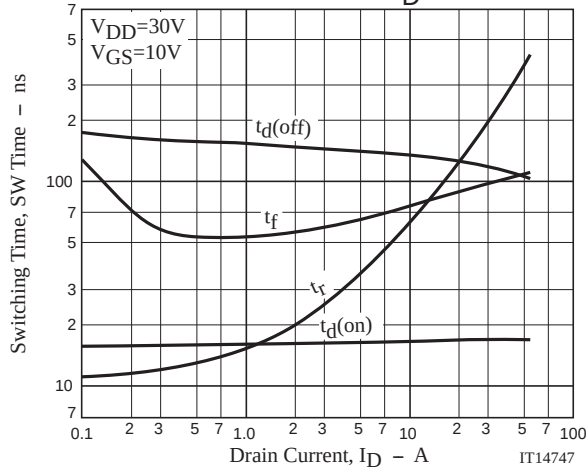
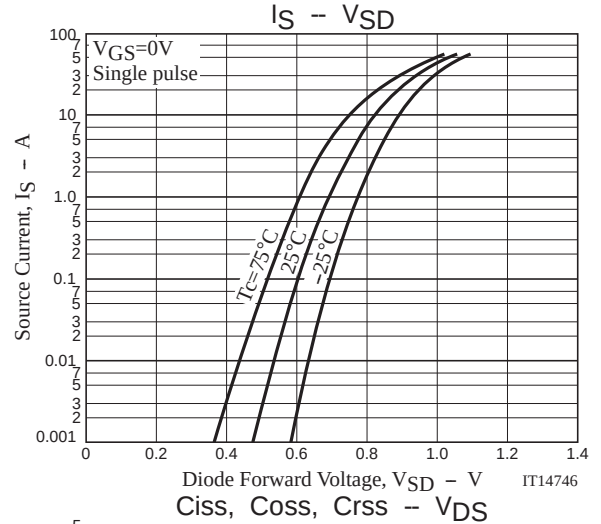
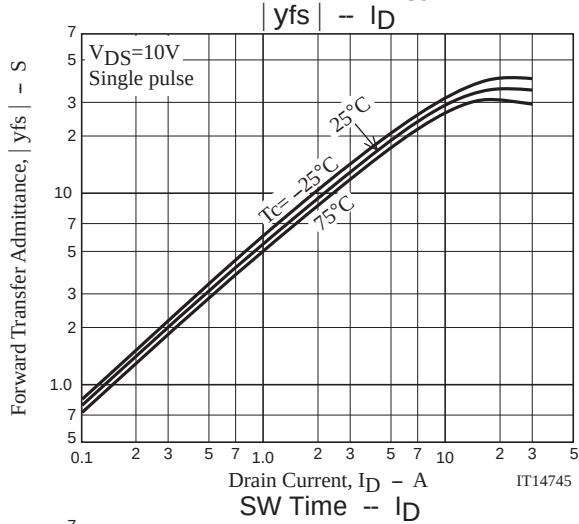
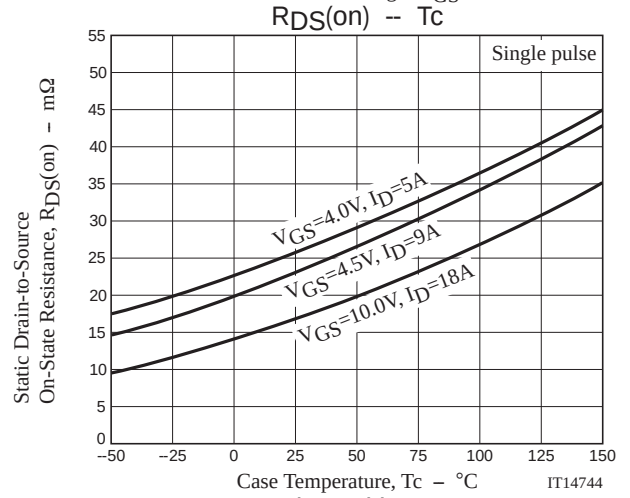
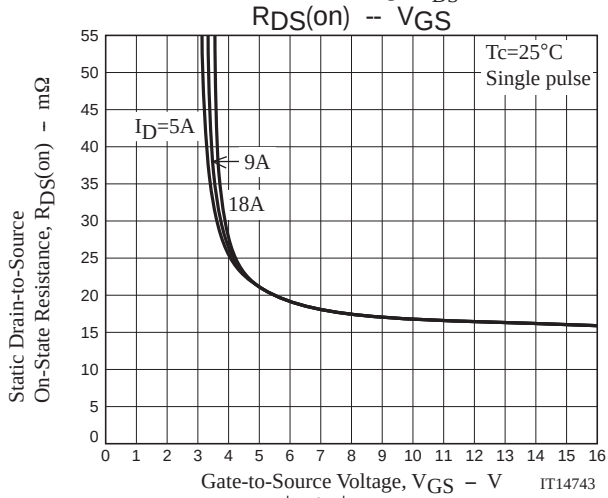
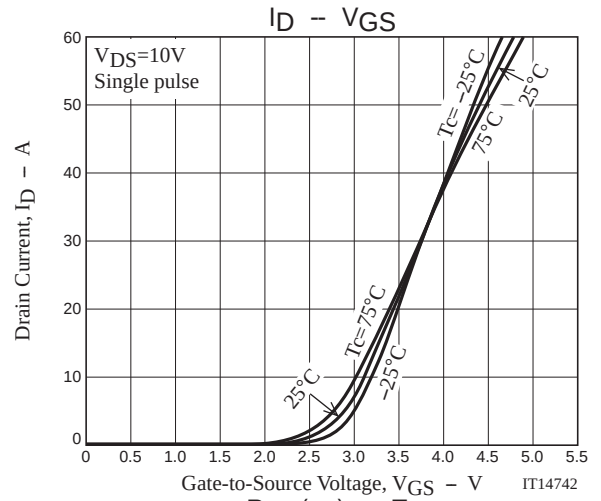
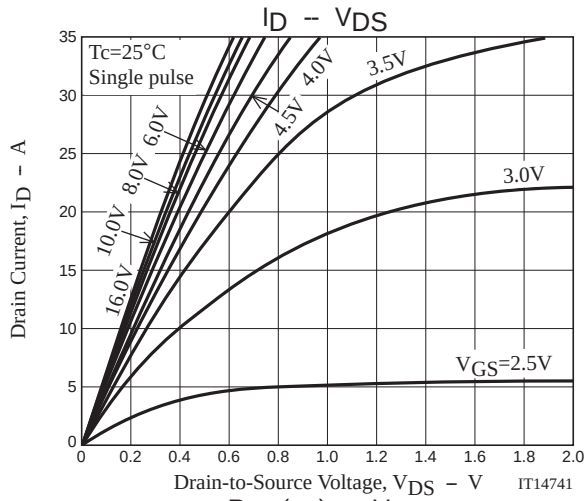
| Parameter                                  | Symbol        | Conditions                        | Ratings |      |          | Unit       |
|--------------------------------------------|---------------|-----------------------------------|---------|------|----------|------------|
|                                            |               |                                   | min     | typ  | max      |            |
| Drain-to-Source Breakdown Voltage          | $V_{(BR)DSS}$ | $I_D=1mA, V_{GS}=0V$              | 60      |      |          | V          |
| Zero-Gate Voltage Drain Current            | $I_{DSS}$     | $V_{DS}=60V, V_{GS}=0V$           |         |      | 1        | $\mu A$    |
| Gate-to-Source Leakage Current             | $I_{GSS}$     | $V_{GS}=\pm 16V, V_{DS}=0V$       |         |      | $\pm 10$ | $\mu A$    |
| Cutoff Voltage                             | $V_{GS(off)}$ | $V_{DS}=10V, I_D=1mA$             | 1.2     |      | 2.6      | V          |
| Forward Transfer Admittance                | $ y_{fs} $    | $V_{DS}=10V, I_D=18A$             |         | 35   |          | S          |
| Static Drain-to-Source On-State Resistance | $R_{DS(on)1}$ | $I_D=18A, V_{GS}=10V$             |         | 17   | 23       | m $\Omega$ |
|                                            | $R_{DS(on)2}$ | $I_D=9A, V_{GS}=4.5V$             |         | 23   | 33       | m $\Omega$ |
|                                            | $R_{DS(on)3}$ | $I_D=5A, V_{GS}=4V$               |         | 25   | 37       | m $\Omega$ |
| Input Capacitance                          | $C_{iss}$     | $V_{DS}=20V, f=1MHz$              |         | 1820 |          | pF         |
| Output Capacitance                         | $C_{oss}$     |                                   |         | 150  |          | pF         |
| Reverse Transfer Capacitance               | $C_{rss}$     |                                   |         | 100  |          | pF         |
| Turn-ON Delay Time                         | $t_d(on)$     | See specified Test Circuit.       |         | 16   |          | ns         |
| Rise Time                                  | $t_r$         |                                   |         | 110  |          | ns         |
| Turn-OFF Delay Time                        | $t_d(off)$    |                                   |         | 125  |          | ns         |
| Fall Time                                  | $t_f$         |                                   |         | 87   |          | ns         |
| Total Gate Charge                          | $Q_g$         | $V_{DS}=30V, V_{GS}=10V, I_D=35A$ |         | 34.5 |          | nC         |
| Gate-to-Source Charge                      | $Q_{gs}$      |                                   |         | 6.5  |          | nC         |
| Gate-to-Drain "Miller" Charge              | $Q_{gd}$      |                                   |         | 6.8  |          | nC         |
| Diode Forward Voltage                      | $V_{SD}$      | $I_S=35A, V_{GS}=0V$              |         | 0.96 | 1.2      | V          |

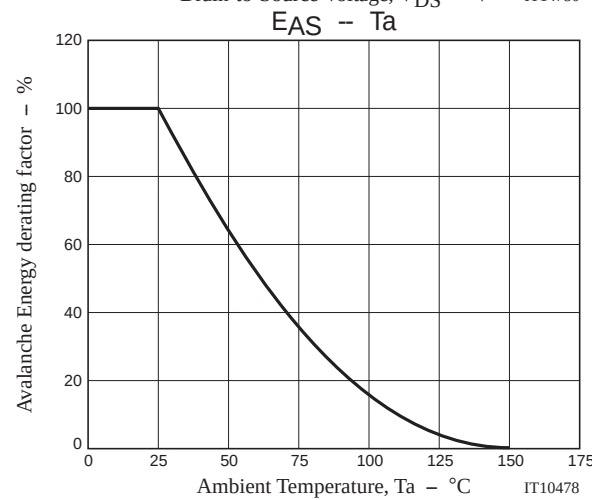
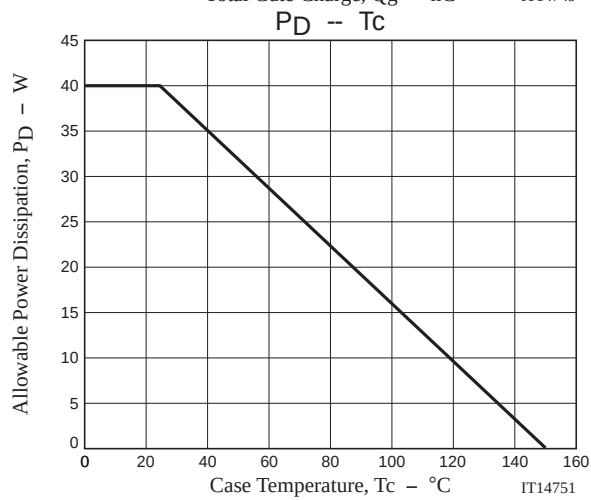
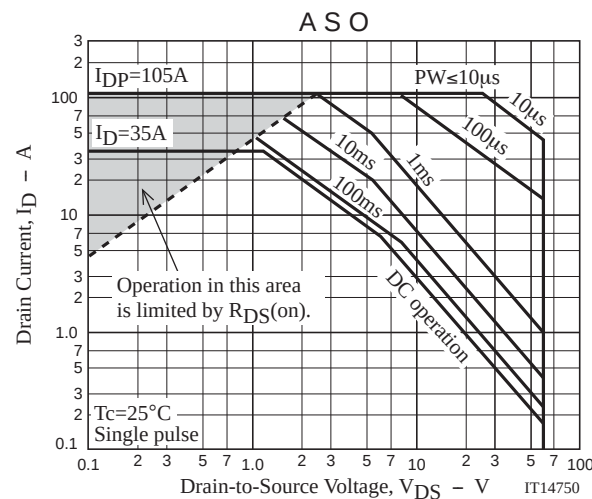
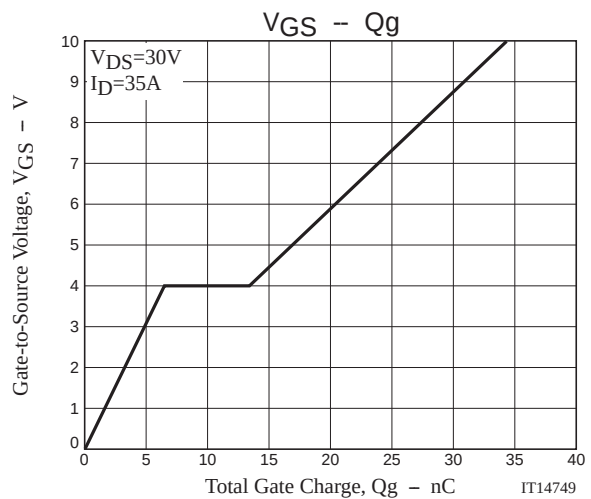
### Switching Time Test Circuit



### Ordering Information

| Device      | Package | Shipping       | memo                     |
|-------------|---------|----------------|--------------------------|
| ATP212-TL-H | ATPAK   | 3,000pcs./reel | Pb Free and Halogen Free |





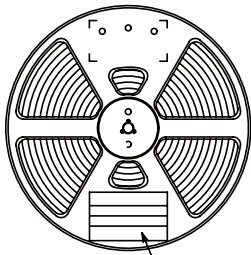
Taping Specification

ATP212-TL-H

1. Packing Format (TL)

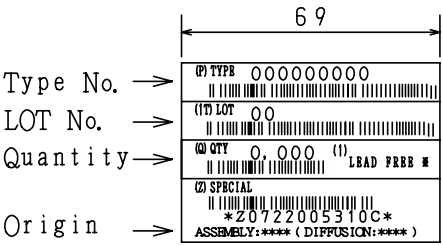
| Package Name | Carrier Tape Type | Maximum Number of devices contained (pcs) |           |           | Packing format                                              |                                                                    |
|--------------|-------------------|-------------------------------------------|-----------|-----------|-------------------------------------------------------------|--------------------------------------------------------------------|
|              |                   | Reel                                      | Inner box | Outer box | INNER BOX SD-C-18                                           | OUTER BOX SD-A-18                                                  |
| ATPAK        | ATP               | 3,000                                     | 3,000     | 15,000    | 1 reels contained<br>Dimensions:mm (external)<br>340×340×28 | 5 inner boxes contained<br>Dimensions:mm (external)<br>355×355×165 |

Packing method



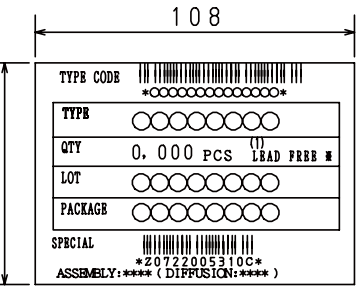
Reel label

Reel label, Inner box label  
(unit:mm)



Outer box label

It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

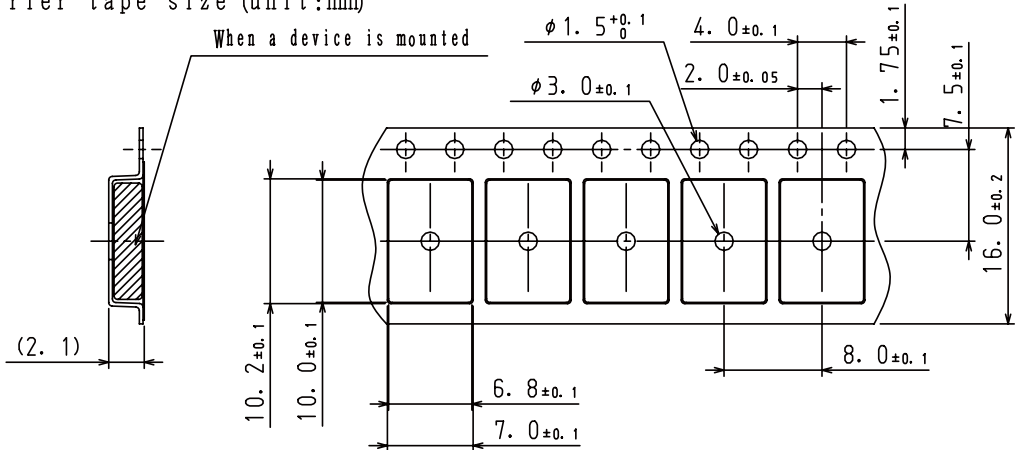


NOTE (1)  
The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

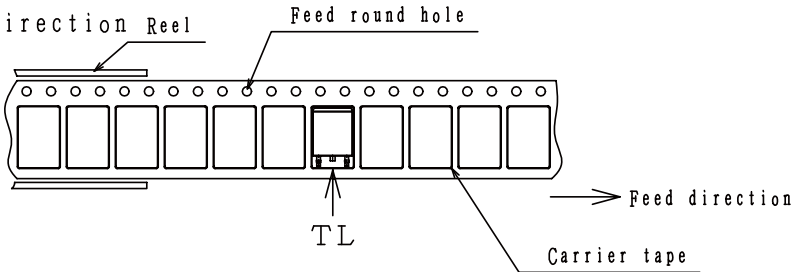
| Label       | JEITA Phase    |
|-------------|----------------|
| LEAD FREE 3 | JEITA Phase 3A |
| LEAD FREE 4 | JEITA Phase 3  |

2. Taping configuration

2-1. Carrier tape size (unit:mm)

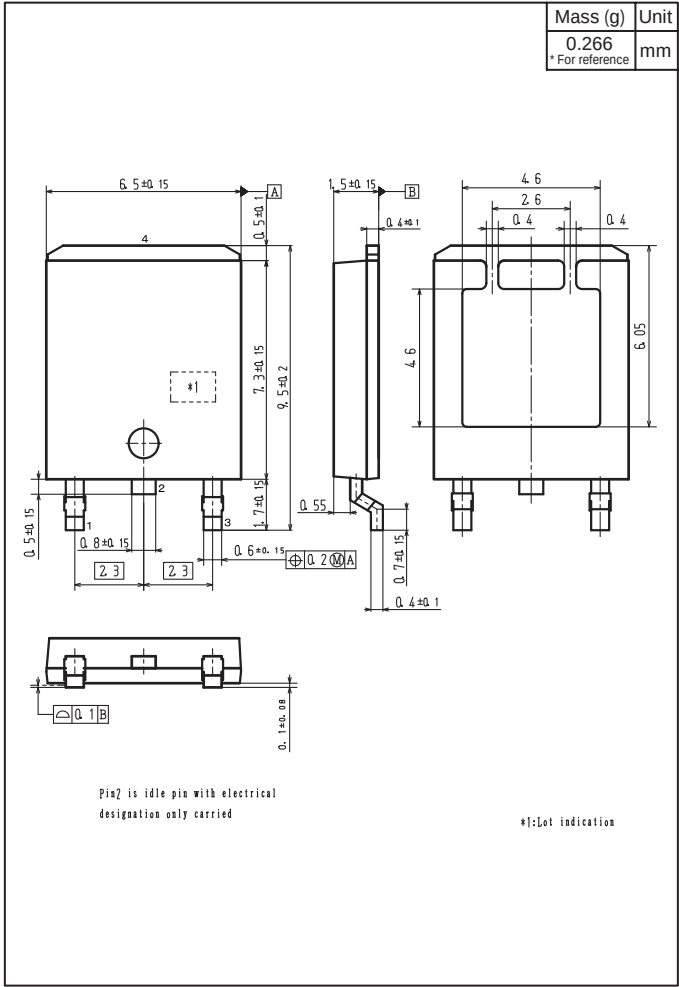


2-2. Device placement direction Reel

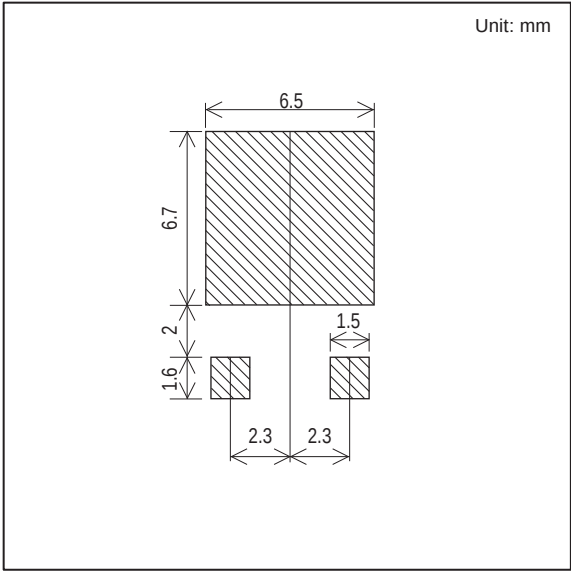


The one electrode terminals on feed hole side...TL

Outline Drawing  
ATP212-TL-H



Land Pattern Example



Note on usage : Since the ATP212 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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